

Features

- Low forward voltage drop
- High reverse voltage
- Hermetic metal cases with ceramic insulators

I_{F(AV)}**1700 A****V_{RRM}****200~1000 V****I_{FSM}****18 KA****I²t****1620 10³A²S****Typical Applications**

- All purpose high power rectifier diodes
- High power resistance welding equipment
- Non-controllable and half-controllable rectifiers
- Controlled rectifiers

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	T _j (°C)	VALUE			UNIT
				Min	Type	Max	
I _{F(AV)}	Mean forward current	180° half sine wave 50Hz Double side cooled,	T _C =85°C	190		1700	A
V _{RRM}	Repetitive peak reverse voltage	tp=10ms		190	200	1000	V
I _{RRM}	Repetitive peak current	at V _{RRM}		190		40	mA
I _{FSM}	Surge forward current	10ms half sine wave	190			18	kA
I ² t	I ² t for fusing coordination	V _R =0.6V _{RRM}				1620	A ² s*10 ³
V _{FO}	Threshold voltage		190			0.81	V
r _F	Forward slope resistance					0.23	mΩ
V _{FM}	Peak forward voltage	I _{FM} =4400A, F=15kN	190			1.82	V
Q _{rr}	Recovery charge	I _{FM} =2000A, tp=2000μs, di/dt=-20A/μs, V _R =50V	190		1900		μC
R _{th(j-c)}	Thermal resistance Junction to case	DC double side cooled				0.035	°C/W
R _{th(c-h)}	Thermal resistance case to heat sink	Clamping force 15.0kN				0.008	
F _m	Mounting force				10	20	kN
T _{stg}	Stored temperature				-40	190	°C
W _t	Weight					240	g
Outline		P39					

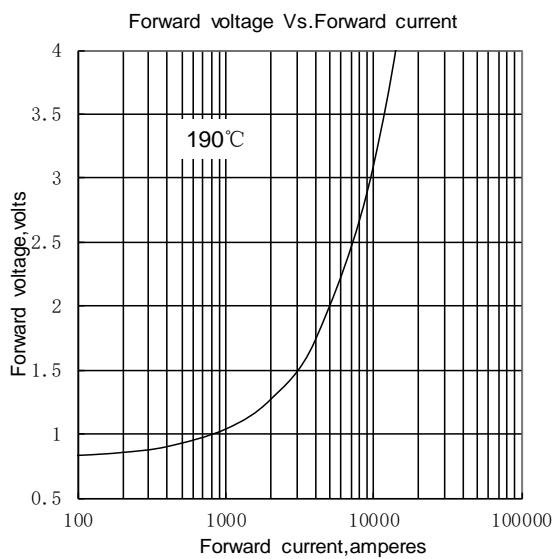


Fig.1

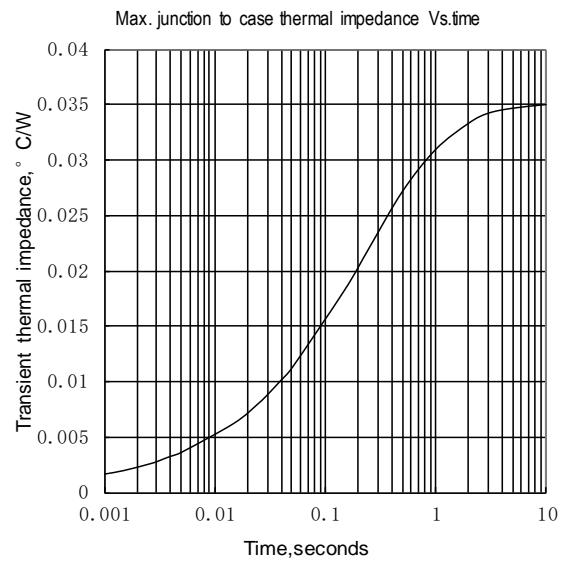


Fig.2

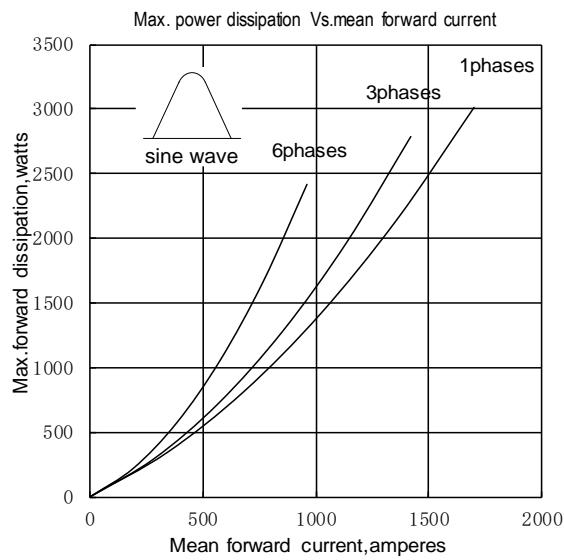


Fig.3

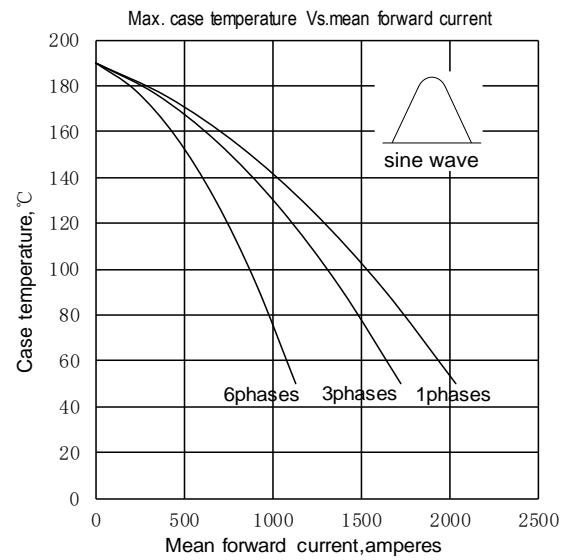


Fig.4

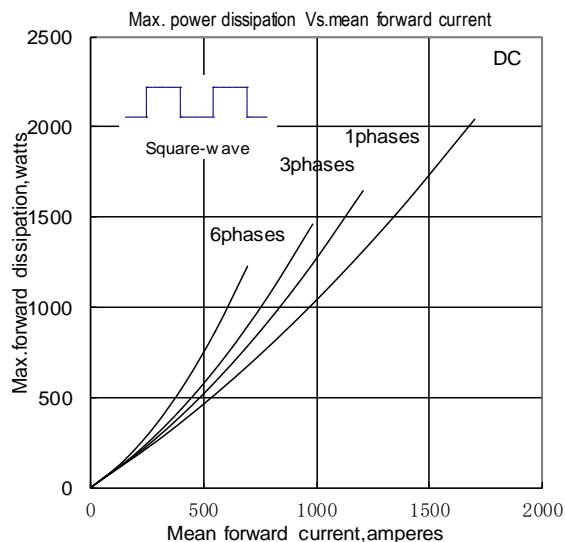


Fig.5

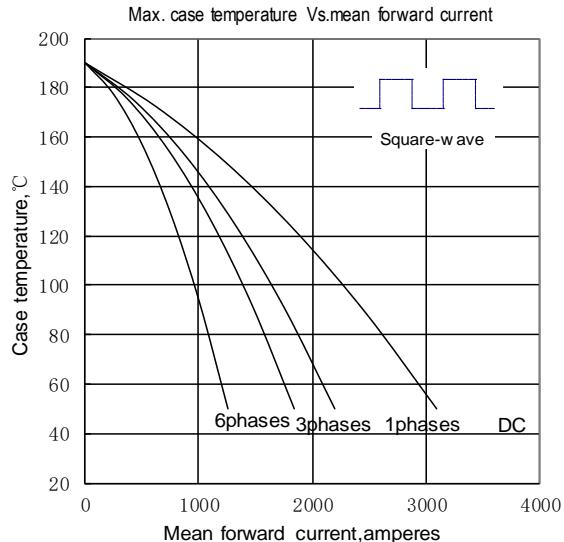


Fig.6

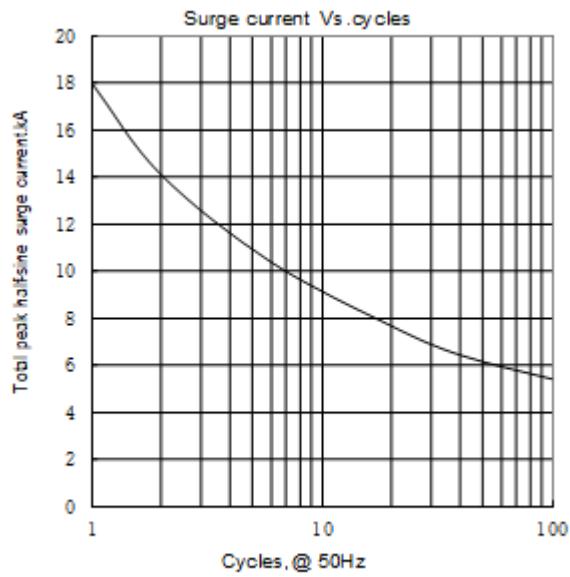


Fig.7

